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Transistor Effects and *In Situ* STM of Redox Molecules at Room Temperature

Tim Albrecht, Adrian Guckian, Jens Ulstrup, and Johannes G. Vos

Abstract—Inorganic transition metal complexes were identified as potential candidates for transistor-like behavior in an electrochemical scanning tunnelling microscope (STM) configuration at room temperature. The theoretical background has been established based on condensed matter charge transfer theory. It predicts a distinct increase of the tunnelling current close to the equilibrium potential, i.e., if molecular bridge states are tuned into resonance with the Fermi levels of the enclosing electrodes. The complexes display robust electrochemistry on Au(111) electrode surfaces. STM images at molecular resolution reveal detailed information on their surface structure and scanning tunnelling spectroscopy experiments have shown clear evidence of transistor-like behavior.

Index Terms—Charge transfer, conductivity, molecular electronics, resonant tunneling transistors, transition metal compounds.

I. INTRODUCTION

OBJECTIVES of emerging nanoscale chemistry at semiconductor and metal surfaces are to map and control the two- or even three-dimensional structure of molecular entities ranging from small organic molecules to transition metal complexes and larger architectures such as proteins, DNA, and dendrimers.

With a view on molecular electronics such as molecular rectification and transistor effects, there is particular interest in understanding and controlling the electronic coupling between the molecular bridge states and electronic levels around the Fermi levels of the enclosing electrodes. This coupling is essentially what induces the desirable pronounced switching effects between “on” and “off” states.

Within the last few years, these concepts have been described both theoretically [1, refs. [7], [8], [10], and [19]–[23] therein] and experimentally [2]–[4] in increasing detail. As a result, functional devices such as switches, rectifiers, diodes, and transistors seem to be within reach. Most studies thus far have, however, concentrated on ultrahigh vacuum, air, or nonconducting low dielectric-constant solvent environments where the target molecules are enclosed in a *two-electrode* configuration. This leaves the bias voltage as the sole external controlling factor. Molecules that have shown molecular switching effects in the form of resonance tunnelling or negative differential

resistance features include organic aromatic thiols [5], amino- and nitro-substituted phenylene ethylenes [6], ferrocene-based molecular entities [7], [8], and phthalocyanines [9], all at Au surfaces in scanning tunnelling microscope (STM) configurations. Other molecular resonance tunnelling systems are organic molecules on Si surfaces [10], [11] and heteropolytungstate anions on highly oriented pyrolytic graphite [12]. Recent cases of single-molecule transistor or amplifier effects of Coulomb staircases, tuned by the gate electrode in three-electrode configurations, have also been reported [13], [14]. In addition to ultrahigh vacuum conditions, these systems, however, also require cryogenic temperatures to operate. On the other hand, operation at room temperature is clearly needed in the approach of new monolayer and single-molecule technologies.

We propose a different approach to investigate switching effects in small molecular entities. It relies on similarities between a three-electrode transistor and a three-electrode electrochemical *in situ* STM configuration, i.e., in an electrochemical environment at room temperature [15]. In such a setup, the analog of source, drain, and gate contacts are the working electrode, STM tip, and reference electrode, respectively. At constant bias, molecular bridge states can be tuned into resonance with the Fermi levels of the tip and working electrode by changing the working electrode potential relative to the reference potential, while the tunnelling current is monitored at a constant bias voltage [scanning tunnelling spectroscopy (STS)] [16], [17]. According to charge transfer theory adapted to such a configuration [18]–[20], the tunnelling current will show a peak feature once resonance is reached, resulting in the desired transistor effect. This resonance is, moreover, expected to be close to the equilibrium redox potential of a particular state if the bias voltage is small.

We have identified inorganic transition metal complexes with Os, Co, and Ru as central ions to be promising candidates for testing these theoretical expectations. These complexes are stable in at least two redox states with low-lying electronic states, their ligand chemistry is robust and well understood, and they can be modified relatively easily, e.g., with respect to the linker group at the metal/molecule interface. With the theoretical frame set and detailed electronic structure calculations on the way, we have obtained experimental evidence of this effect by *in situ* STM and STS combined with a variety of electrochemical techniques on atomically planar single-crystal gold and platinum surfaces.

II. EXPERIMENTAL

All chemicals were of highest available grade, H₂O was supplied by a Millipore system (Milli-Q Housing). The complexes [Os(bpy)₂(p0p)₂](PF₆)₂ (**1**) and [Os(pby)₂(p2p)₂](PF₆)₂ (**2**)

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were prepared by refluxing $[\text{Os}(\text{bpy})_2\text{Cl}_2]\cdot 2\text{H}_2\text{O}$ and AgNO_3 in a 1 : 1 ethylene glycol/ H_2O solution until a grey precipitate was formed. After removing the precipitate, either p0p or p2p were added and refluxing continued for 96 h. After removing unreacted ligand and addition of a concentrated aqueous solution of ammonium hexaphosphate, the product was washed with H_2O , dried with diethylether, and purified by column chromatography. The identity of the compounds was checked by NMR spectroscopy on a Bruker Avance 400 (400 MHz) spectrometer (bpy = 2,2'-bipyridyl; p0p = 4,4'-bipyridyl; p2p = 1,2-bis(-4-pyridyl)ethane).

Au(111) electrodes were prepared as published before [21]. For STM, an Au(111) disc electrode ($d = 10$ mm) was purchased from Surface Preparation Laboratory, Zaandam, The Netherlands. Electrodes were annealed in an H_2 -flame, cooled in H_2O -saturated air, and transferred to the stock solution of a particular complex immediately.

The stock solutions were prepared in a concentration range of 10–100 μM in a mixture of $\text{H}_2\text{O}/\text{DMF}$ 2 : 1 (m/m). Electrodes were soaked overnight, then rinsed with Millipore H_2O and electrolyte (0.1 M HClO_4).

An electrochemical Autolab system controlled by a GPES software package (Ecochemie, Utrecht, The Netherlands) was used including custom-made electrochemical (glass) cells. A freshly prepared reversible hydrogen electrode (RHE) and a Pt wire served as the reference and counter electrode, respectively. The reference potential was checked with a saturated calomel electrode (SCE) after each experiment. The Au(111) electrodes were employed in a hanging-meniscus configuration. Prior to each experiment, the electrochemical cell was deoxygenated by purified Ar (Chrompack O_2 filter) and a steady flow of Ar was maintained at all times during operation.

A PicoSPM instrument (Molecular Imaging, Tempe, AZ) with a bipotentiostat for independent control of substrate and tip potential was used in a constant-current mode. The custom-made three-electrode Teflon cell was equipped with two Pt wires serving as the reference and counter electrodes. The reference potential was checked with an SCE reference electrode after each experiment. The concentration of either (1) or (2) in the electrolyte was in the range of 1–10 μM .

III. THEORY

The theoretical background of room-temperature molecular transistor functionality is described in the literature [1, refs. [7], [8], [10], and [19]–[23] therein], [18]–[20]. In the fully adiabatic case where both electron transfer steps, working electrode/bridge, and bridge/tip accord with the adiabatic limit of strong coupling between the molecule and the enclosing electrodes, the tunnelling current can be described by (1) assuming two symmetric metal contacts

$$i_{\text{tunn}}^{\text{ad}} = \frac{1}{2} \cdot e\kappa\rho(eV_{\text{bias}}) \cdot \frac{\omega_{\text{eff}}}{2\pi} \cdot \exp\left(-\frac{E_R + eV_{\text{bias}}}{4k_B T}\right) \times \cosh^{-1}\left[\frac{\left(\frac{1}{2} - \gamma\right)eV_{\text{bias}} - e\xi\eta}{2k_B T}\right] \quad (1)$$

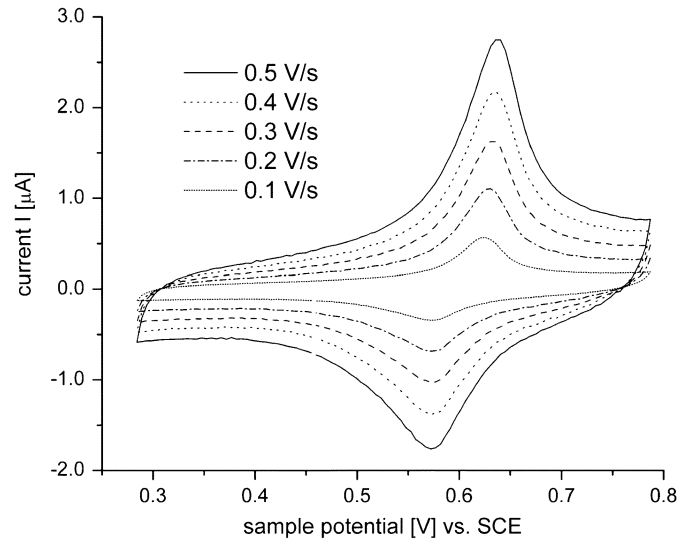


Fig. 1. CVs of compound (1) at different scan rates ν from 0.1 to 0.5 V/s, electrolyte: 0.1 M HClO_4 .

where κ is the transmission coefficient, ρ is the level density in the two metals, ω_{eff} is a characteristic (nuclear) frequency, E_R is the molecular and environmental reorganization free energy, γ and ξ are the fractional potential drops of bias and sample potential at the redox center, and η is the overpotential, i.e., the difference between the equilibrium and sample potentials. All other parameters have their usual meaning.

If the bias potential drop γ at the redox center equals one-half, the maximum of the tunnelling current is found at $\eta = 0$, i.e., at the equilibrium potential. By modulating the working electrode potential, molecular redox levels can thus be tuned in and out of resonance, resulting in an “on” and “off” state analogous to a transistor-like device. For a detailed description of the electronic properties of such a device, theoretical frames need to be substantiated by experimental data, specifically regarding the metal/bridge interface and the central metal ion.

IV. EXPERIMENTAL RESULTS

Prior to any *in situ* STM experiment, the stability of the electrochemical response from complexes (1) and (2) and a corresponding potential window was characterized by cyclic voltammetry on single-crystal Au(111) electrodes, as shown in Fig. 1.

A plot of the peak current I_p versus the scan rate ν yielded a linear correlation, indicating that the observed electron transfer process indeed originates from a surface-confined species (not shown). The electrochemical response was stable for at least several hundred potential scans.

In situ STM investigations under the same conditions have revealed that the monolayers of both compounds (1) and (2) consist of two different domain types.

The major part of the electrode surface seems to be disordered, but some areas display highly ordered structures where images of molecular resolution were obtained. Fig. 2 shows a high-resolution *in situ* STM image of compound (2).

A double-striped feature is clearly visible, which is composed of two individual lines each displaying molecular substructure. The length of such an individual line is approximately 19 Å.

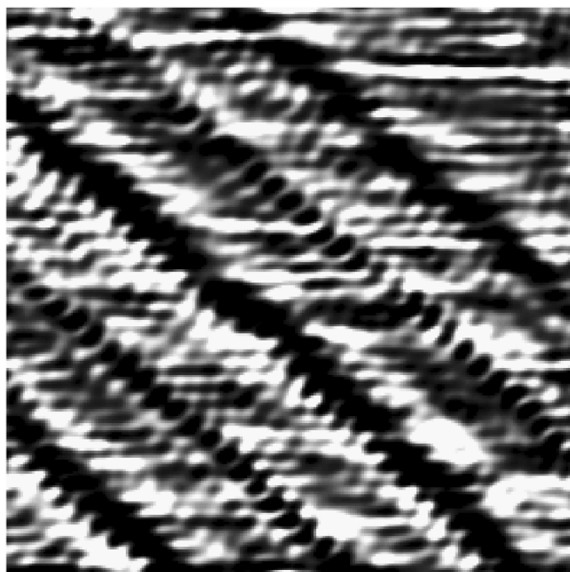


Fig. 2. *In situ* STM image of compound (2) in 0.1 M HClO₄. Area: (12.5 nm)², $E_s = +0.25$ V, $V_{\text{bias}} = -0.2$ V, $I_{\text{set}} = 50$ pA (all potentials versus SCE). Tip material: W.

This is very similar to the length of (2) along one of the linker ligands p2p (ca. 17 Å). We, therefore, conclude that, at least in the highly ordered domains, only one ligand is bound to the surface, while the other one points into the solution, presumably being protonated. This finding is in line with previous work by Forster *et al.* who came to the same conclusion for a comparable complex [Os(bpy)₂(p3p)₂](PF₆)₂, based on electrochemical data [22].

After repetitive cycling of the sample potential in the range shown in Fig. 1, the ordered domains disappear and only the disordered phase is observed.

In order to probe the dependence of the tunnelling current I_t on the sample potential E_s for compound (2), the feedback loop was switched off. With the tip still in the tunnelling range, E_s was cycled from -0.05 to $+0.8$ V at a constant bias voltage and I_t was monitored. A typical sweep lasted 10 s and only those scans were included in the data evaluation where the tunnelling current only changed insignificantly before and after a potential sweep (minimal vertical drift). From *in situ* STM imaging, the lateral drift was estimated to be around 10 Å during a potential sweep.

The result of averaging 20 subsequent *in situ* STS scans is shown in Fig. 3, together with a cyclovoltammogram (CV) of (2).

The *in situ* STS curve shows a clear peak-like feature around the equilibrium potential of the complex.

Upon retracting the tip from the surface, i.e., out of the tunnelling range, the peak vanishes completely, showing that the observed feature indeed refers to a resonant tunnelling effect. Additional experiments on bare Au(111), with a different tip material (W) and electrolyte (HNO₃) have supported this interpretation. It could be shown that purely Faradaic effects, such as the oxidation/reduction of a bare gold surface, do not cause any change in the tunnelling current (not shown).

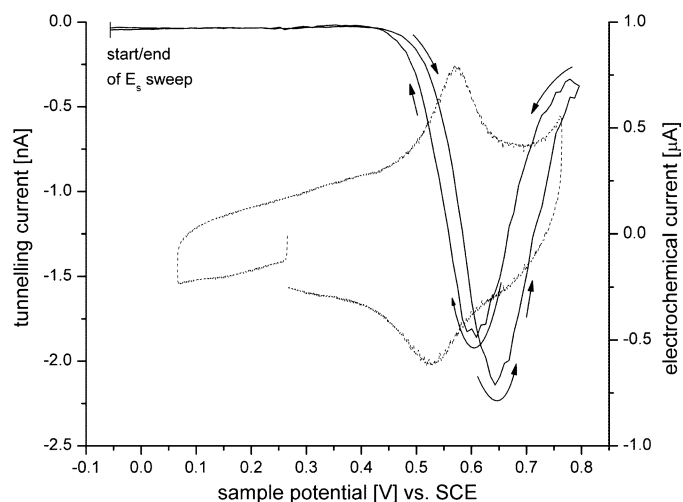


Fig. 3. *In situ* STS curve (solid line, left-hand-side ordinate) and CV (dashed line, right-hand-side ordinate) of compound (2) in 0.1-M HClO₄. STS: E_s scan range from -0.05 to $+0.8$ V, $V_{\text{bias}} = -0.1$ V. Sweep duration: 10 s. Tip material: Pt/Ir (80/20). CV: $\nu = 0.1$ V/s (all potentials versus SCE). Note the different ordinate scales.

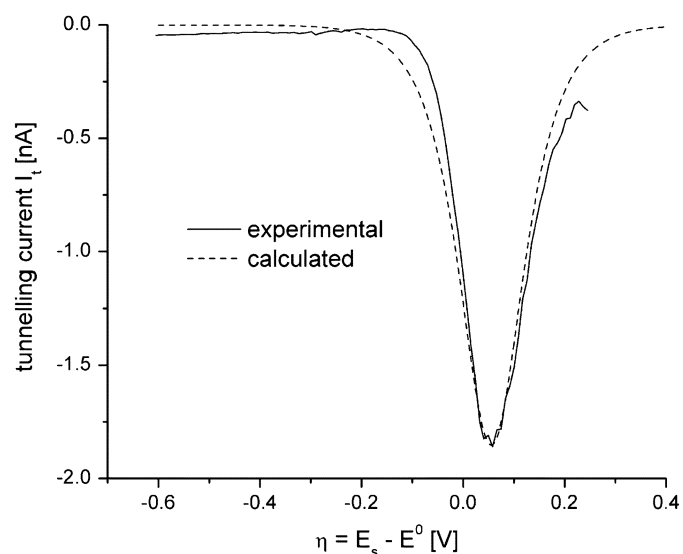


Fig. 4. Experimental and simulated *in situ* STS correlations according to (1) (solid and dashed lines, respectively). $E_R = 0.5$ eV, $V_{\text{bias}} = -0.1$ V, $\gamma = 1$, $\xi = 0.9$, $\kappa \cdot \rho \cdot \omega_{\text{eff}} \cdot e^2 / (4 \cdot \pi) = 9.1 \cdot 10^{-7}$ C²/(eV · s). Experimental data from reverse scan (from high-to-low potentials) in Fig. 3.

If the observed peak was due to Faradaic effects, the measured current should change sign upon reversing the scan direction, as in cyclovoltammetry. This is not the case.

The peak position depends slightly on the sweep direction, as shown in Fig. 3. This effect could be related to dielectric relaxation in the tunnelling gap in response to the potential sweep since the peak separation decreases with increasing sweep duration.

Independent of sweep direction, the tunnelling current peaks at a slightly higher sample potential than the electrochemical equilibrium potential in CV. This is, however, in accordance with (1), as the immobilized redox center is located closer to the tip than to the substrate and experiences a fraction of the bias voltage $\gamma > 0.5$ in addition to the sample potential.

A simulation based on (1) shows that the adiabatic charge transfer model can indeed reproduce the peak position, shape, and, to a reasonable approximation, also its intensity (Fig. 4).

At the current stage, it is difficult to draw conclusions from the absolute intensity of the peak since the true distance between the tip, redox center, and surface is not accurately known. Both nonvanishing vertical and lateral drift in the *in situ* STM experiments at room temperature complicate the situation. As the observed peak is most probably due to a single or a very small number of molecules, there may also be some dispersion in their electrochemical and tunnelling properties. Its multielectronic nature will, however, lead to some temporal averaging. The actual ratio between peak and background intensity, in terms of an "on"/"off" ratio, amounts to approximately 50 (Fig. 3).

V. CONCLUSION

We have synthesized two compounds of a larger class of transition metal complexes identified as promising candidates for displaying transistor-like features in their molecular electronic conductivity at room temperature and in an electrochemical environment. The theoretical framework has been established. The electrochemical characterization of both compounds has shown that they form self-assembled monolayers on Au(111). STM images to molecular resolution have been obtained that allow for insight into details of their surface organization. Their electrochemical properties support our design strategy. Detailed STS investigations have provided evidence of resonant tunnelling effects related to the redox state of the metal complex. Further experiments are on the way to probe the electronic properties of the molecules at the single-molecule level and to elucidate the role of the central metal ion and the linker group to the electrode surface.

REFERENCES

- [1] A. M. Kuznetsov and J. Ulstrup, "Single-molecule electron tunnelling through multiple redox levels with environmental relaxation," *J. Electroanal. Chem.*, vol. 564, pp. 209–222, 2004.
- [2] R. M. Metzger, "Unimolecular electrical rectifiers," *Chem. Rev.*, vol. 103, pp. 3803–3834, 2003.
- [3] A. Aviram, M. Ratner, and V. Mujica, Eds., *Molecular Electronics II*. New York: New York Acad. Sci., 2002.
- [4] J. G. Kushmerick *et al.*, "Understanding charge transport in molecular electronics," in *Molecular Electronics III*, J. R. Reimers, C. A. Picconatto, J. C. Ellenbogen, and A. Shashidar, Eds. New York: New York Acad. Sci., 2003, vol. 1006, pp. 277–290.
- [5] Y. Xue, S. Datta, S. Hong, R. Reifenberger, J. I. Henderson, and C. P. Kubiak, "Negative differential resistance in the scanning-tunneling spectroscopy of organic molecules," *Phys. Rev. B, Condens. Matter*, vol. 59, pp. R7852–R7855, 1999.
- [6] F. F. Fan, J. Yang, L. Cai, D. W. Price, Jr., S. M. Dirk, D. V. Kosynkin, Y. Yao, A. M. Rawlett, J. M. Tour, and A. J. Bard, "Charge transport through self-assembled monolayers of compounds of interest in molecular electronics," *J. Amer. Chem. Soc.*, vol. 124, pp. 5550–5560, 2002.
- [7] C. B. Gorman, R. L. Carroll, and R. Fuijrer, "Negative differential resistance in patterned electroactive self-assembled monolayers," *Langmuir*, vol. 17, pp. 6923–6930, 2001.
- [8] R. A. Wassel, G. M. Credo, R. R. Fuijrer, D. L. Feldheim, and C. B. Gorman, "Attenuating negative differential resistance in an electroactive self-assembled monolayer-based junction," *J. Amer. Chem. Soc.*, vol. 126, pp. 295–300, 2004.
- [9] L. Scudiero, D. E. Barlow, and K. W. Hipps, "Physical properties and metal ion specific scanning tunneling microscopy images of metal(II) tetraphenylporphyrins deposited from vapor onto gold(111)," *J. Phys. Chem. B*, vol. 104, pp. 11 899–11 905, 2000.

- [10] N. P. Guisinger, M. E. Greene, R. Basu, A. S. Baluch, and M. C. Hersam, "Room temperature negative resistance through individual organic molecules on silicon surfaces," *Nano Lett.*, vol. 4, pp. 55–59, 2004.
- [11] —, "Observed suppression of room temperature negative differential resistance in organic monolayers on Si(100)," *Nanotechnology*, vol. 15, pp. S452–S458, 2004.
- [12] M. S. Kaba, I. K. Song, and M. A. Barteau, "Ordered array formation and negative differential resistance behavior of cation-exchanged heteropoly acids probed by scanning tunneling microscopy," *J. Phys. Chem.*, vol. 100, pp. 19 577–19 581, 1996.
- [13] S. Kubatkin *et al.*, "Single-electron transistor of a single organic molecule with access to several redox states," *Nature*, vol. 425, pp. 698–701, 2003.
- [14] J. Park *et al.*, "Coulomb blockade and the Kondo effect in single-atom transistors," *Nature*, vol. 417, pp. 722–725, 2002.
- [15] D. M. Kolb, "Electrochemical surface science," *Angew. Chem. Int. Ed.*, vol. 40, pp. 1162–1181, 2001.
- [16] N. J. Tao, "Probing potential-tuned resonant tunneling through redox molecules with scanning tunneling microscopy," *Phys. Rev. Lett.*, vol. 76, pp. 4066–4069, 1996.
- [17] W. Haiss *et al.*, "Redox state dependence of single molecule conductivity," *J. Amer. Chem. Soc.*, vol. 125, pp. 15 294–15 295, 2003.
- [18] A. M. Kuznetsov and J. Ulstrup, "Mechanisms of *in situ* scanning tunneling microscopy of organized redox molecular assemblies," *J. Phys. Chem. A*, vol. 104, pp. 11 531–11 540, 2000.
- [19] —, "Errata of 'Mechanisms of *in situ* scanning tunneling microscopy of organized redox molecular assemblies,'" *J. Phys. Chem. A*, vol. 105, p. 7494, 2001.
- [20] J. Zhang *et al.*, "Electronic properties of functional biomolecules at metal/aqueous solution interfaces," *J. Phys. Chem. B*, vol. 106, pp. 1131–1152, 2002.
- [21] J. Clavilier *et al.*, "The role of anion on the electrochemical behaviour of a 111 platinum surface: An unusual splitting of the voltammogram in the hydrogen region," *J. Electroanal. Chem.*, vol. 107, pp. 205–209, 1980.
- [22] R. J. Forster and J. P. O'Kelly, "pH modulated heterogeneous electron transfer across metal/monolayer interfaces," *J. Phys. Chem.*, vol. 100, pp. 3695–3704, 1996.



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